

Single Layer Timepix3 Compton Camera

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Timepix3:

- Successor of Timepix: 256x256 pixels, 55 μm pitch
- Event based readout (Not frame based as for Timepix): Each hit pixel transmits the hit information immediately.
- \Rightarrow No dead-time for readout of complete frame.
- Ability to measure Energy (ToT) and Time of arrival (ToA) concurrently.
- Time is measured with precision of 1.56 ns
- Chip can produce data stream of 5 Gbit/s.







X Timepix3 + different sensor types

Supported sensor types:

- Silicon 100-1000 µm thick: Particle tracking, electron microscopy ...
- CdTe 1000 and 2000 μm thick: Hard X-rays, Gamma, PET, SPECT \ldots
- CZT 2000 µm thick
- GaAs 625 µm thick





MiniPIX TPX3 - Miniaturized spectral camera supporting Si and CdTe sensors

- Miniaturized and compact device
- Vacuum compatible
- USB 2.0 device
- Bias source from -500 to + 300 V
- FPGA and ARM processor
 - ARM processor flexible can be programmed to work autonomously
- Sync. communication among multiple devices
- Possible to combine with different sensors
 - Si (100 1000 um),
 - CdTe (1 mm)
 - CZT (2 mm) coming
- Maximal frame rate: 16 frames / s



Its really small ..





Gamma spectrum reconstruction for CdTe

- 2 mm thick CdTe sensor: Efficiency for 120 keV of about 70%
- · Coincidence technique removes artifacts and suppresses internal Compton scattering



Internal XRF reconstruction:

- 1. Coincident events E1, E2 recognized
- 2. One of them fits to XRF energy of Cd or Te say E2
- 3. Event E2 is removed.
- 4. Energy E=E1+E2 is assigned to E1.



Compton effect reconstruction:

- 1. Coincident events E1, E2 recognized
- 2. Compton and Klein-Nishina formula evaluated for E1 and E2
- 3. More likely scattering scenario is chosen
- 4. Energy E=E1+E2 is assigned to correct point.

N Depth difference measurement in CdTe

· Pair of events occurring in different depths of the sensor

Time Insl

- Use time of charge collection
- Calibration with cosmic muons

Bias voltage of 450 V: Time domain



Bias voltage of 200 V: Time domain



ADVACAM

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Muon3 time

0.8 Depth Immi



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Depth resolution: 28.5 μm (RMS)

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Compton Scattering and Compton Camera

Compton scattering

- Scattering of photon by a charged particle (electron) in a material
- Decrease in energy of the photon
- Part of the energy transferred to the recoiling electron

Compton camera principle

- Typically two detectors
- First detector scatterer
- Second detector absorber
- Reconstruction of cones, their intersection
- For each Compton scattering event we can:
- Detect coincidence

<u>A D V A C A M</u>

- Measure both energies: E₁ and E₂
- Measure both positions in 3D

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=> We can reconstruct Compton cone:





T h







Timepix3 CdTe detector





Timepix3 CdTe detector





























































$E_0 = E_1 + E_2$ $\cos \theta = 1 - m_e c^2 \frac{E_1}{E_2(E_1 + E_2)}$















































Single Layer Compton Camera with MiniPIX TPX3 + 2mm CdTe – 133Ba source



Reconstruction of position of 4¹³³Ba gamma sources (356 keV)



Single Layer Compton Camera with MiniPIX TPX3 – 131 lodine source

Second test – ¹³¹Iodine gamma source

- 3 different lodine solutions in small bottles positioned in a room at different positions
- Distance from detector 3.5 m
- Mapped on photograph of the room
- Sources located correctly



Energy Spectrum of ¹³¹I



Reconstruction of position of three ¹³¹I gamma sources (364 keV)



Single Layer Compton Camera with MiniPIX TPX3 – 137 Cesium source

Third Test – ¹³⁷Cesium gamma source

- Weak source 100 kBq
- Distance from detector 10 cm
- Source localized









Fourth Test – 3 different gamma sources ¹³⁷Cs, ²²Na, ¹³¹I

- Distance from the detector 7 cm
- Different energies (364 keV, 511 keV, 662 keV)







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100 – 150 keV







150 – 200 keV







200 – 250 keV







250 – 300 keV







300 – 350 keV







350 – 400 keV







400 – 450 keV







450 – 500 keV







500 – 550 keV







550 – 600 keV







600 – 650 keV







650 – 700 keV







700 – 750 keV









Gamma camera applications: Thyroid diagnostics

Thyroid cancer diagnostics and treatment monitoring:

- The second most frequent cancer for women (after breast cancer)
- Current imaging methods offer resolution of about 12 mm in 2D
- Our technology allows
 - 5 times better resolution and 3D (2.5 mm)
 - 4 times lower dose



- Principle:
 - Single layer Compton camera





Gamma camera applications: Source localization

- Localization of isotopes in an environment
 - Nuclear powerplant
 - Radioactive waste
- Combined with MiniPIX TPX3
 - Small device
 - Very light
 - Handheld
- Localization of sources
 - Mounted on a helicopter
 - Drones







- MiniPIX TPX3 a new miniaturized Timepix3 readout device
- Takes advantages of Timepix3 chip, slower than faster devices like AdvaPIX TPX3, but low power and small size
- Can be integrated in other systems
- Allows many different applications
- Single layer Timepix3 Compton camera possible with Timepix3 and MiniPIX
- Can localized isotopes in an environment
- Recognize different sources (different energies)
- Allows many new applications (SPECT, thyroid diagnostics ...)







Thank you for your attention





